

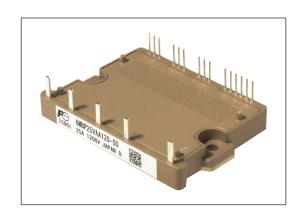
6MBP25VAA120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 25A / IPM

■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- · Low power loss and soft switching
- · High performance and high reliability IGBT with overheating
- · Higher reliability because of a big decrease in number of parts in built-in control circuit



■ Maximum Ratings and Characteristics

◆ Absolute Maximum Ratings (T_c=25°C, V_{cc}=15V unless otherwise specified)

Items		Symbol	Min.	Max.	Units
Collector-Emitter Voltage (*1)		V _{CES}	0	1200	V
Short Circuit Voltage		Vsc	400	800	V
	DC	Ic	-	25	А
Collector Current	1ms	I _{cp}	-	50	Α
	Duty=100% (*2)	-lc	-	25	Α
Collector Power Dissipation	1 device (*3)	Pc	-	166	W
Supply Voltage of Pre-Driver (*4	l)	Vcc	-0.5	20	V
Input Signal Voltage (*5)		Vin	-0.5	Vcc+0.5	V
Alarm Signal Voltage (*6)		V _{ALM}	-0.5	Vcc	V
Alarm Signal Current (*7)		IALM	-	20	mA
Junction Temperature		T _i	-	150	°C
Operating Case Temperature		Topr	-20	110	°C
Storage Temperature		T _{stg}	-40	125	°C
Solder Temperature (*8)		T _{sol}	-	260	°C
Isolating Voltage (*9)		Viso	-	AC2500	Vrms
Screw Torque	Mounting (M4)	-	-	1.7	Nm

Note *1: V_{CES} shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W)-N. Note *2: $Duty=125^{\circ}C/R_{(h(J-c)D)}/(I_F\times V_F Max.)\times 100$

Note *3: Pc=125°C/Rth(j-c)Q

Note *4: Voc shall be applied to the input voltage between terminal No.3 and 1, 6 and 4, 9 and 7,11 and 10. Note *5: V_{II} shall be applied to the input voltage between terminal No.2 and 1, 5 and 4, 8 and 7,12~14 and 10.

Note *6: VALM shall be applied to the voltage between terminal No.15 and 10.

Note *7: IALM shall be applied to the input current to terminal No.15. Note *8: Immersion time 10±1sec. 1time

Note *9: Terminal to base, 50/60Hz sine wave 1min. All terminals should be connected together during the test.

● Electrical Characteristics (Tj=25°C, Vcc=15V unless otherwise specified)

Ite	Items		Conditions		Min.	Тур.	Max.	Units
	Collector Current at off signal input	Ices	V _{CE} =1200V		-	-	1.0	mA
ē	Collector Emitter activation voltage		Ic=25A	Terminal	-	-	2.10	V
nverter	Collector-Emitter saturation voltage	V _{CE(sat)}		Chip	-	1.68	-	V
=	Forward voltage of FWD	V _F	I _F =25A	Terminal	-	-	2.60	V
	Forward voltage of FWD	VF		Chip	-	2.10	-	V
		ton	V _{DC} =600V, T _i =125°C, I _C =25A		1.1	-	-	μs
e,	vitching time	toff	VDC-000V, 1j-12	25 C, IC-25A	-	-	2.1	μs
34	Switching time		V _{DC} =600V, I _F =25A		-	-	0.3	μs
Sı	upply current of P-side pre-driver (per one unit) Icop Switching Frequency= 0-15kHz		ency= 0-15kHz	-	-	9	mA	
Sı	pply current of N-side pre-driver	Iccn	Tc=-20~110°C		-	-	23	mA
In	Input signal threshold voltage	V _{inth(on)}	V _{in} -GND	ON	1.2	1.4	1.6	V
1111		Vinth(off)		OFF	1.5	1.7	1.9	V
O	ver Current Protection Level	r Current Protection Level loc T _j =125°C			38	-	-	Α
O	Over Current Protection Delay time		T _j =125°C		-	5	-	μs
Sł	ort Circuit Protection Delay time	tsc	T _j =125°C		-	2	3	μs
IG	BT Chips Over Heating Protection Temperature Level	Тјон	Surface of IGBT	Chips	150	-	-	°C
O	ver Heating Protection Hysteresis	Тјн			-	20	-	°C
Ur	nder Voltage Protection Level	Vuv			11.0	-	12.5	V
Ur	nder Voltage Protection Hysteresis	V _H			0.2	0.5	-	V
	Alarm Signal Hold Time		AL MA ONID		1.0	2.0	2.4	ms
Al			ALM-GND T _c =-20~110°C	Vcc≧10V	2.5	4.0	4.9	ms
			10 20 110 0		5.0	8.0	11.0	ms
Re	esistance for current limit	RALM			960	1265	1570	Ω

● Thermal Characteristics (Tc = 25°C)

Items			Symbol	Min.	Тур.	Max.	Units
lunction to Cook Thermal Besistance (*40)	Inverter	IGBT	R _{th(j-c)Q}	-	-	0.75	°C/W
Junction to Case Thermal Resistance (*10)		FWD	R _{th(j-c)D}	-	-	1.40	°C/W
Case to Fin Thermal Resistance with Compound			R _{th(c-f)}	-	0.05	-	°C/W

Note $^{\star}10$: For 1device, the measurement point of the case is just under the chip.

● Noise Immunity (V_{DC}=600V, V_{CC}=15V)

Items	Conditions	Min.	Тур.	Max.	Units
Common mode rectangular noise	Pulse width 1µs, polarity ±, 10 min. Judge : no over-current, no miss operating	±2.0	-	-	kV

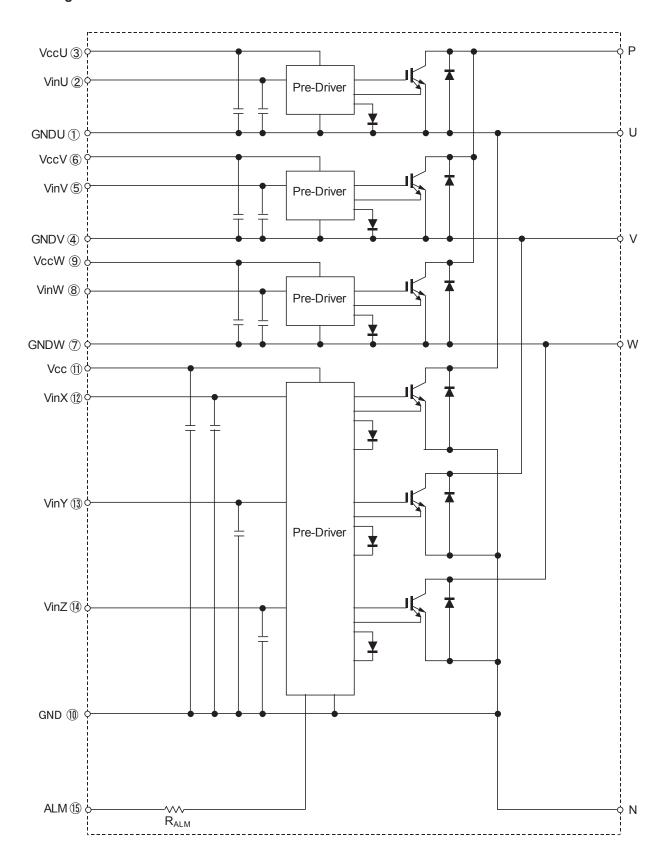
Recommended Operating Conditions

Items	Symbol	Min.	Тур.	Max.	Units
DC Bus Voltage	V _{DC}	-	-	800	V
Power Supply Voltage of Pre-Driver	Vcc	13.5	15.0	16.5	V
Switching frequency of IPM	fsw	-	-	20	kHz
Arm shoot through blocking time for IPM's input signal	t _{dead}	1.0	-	-	μs
Screw Torque (M4)	-	1.3	-	1.7	Nm

Weight

Items	Symbol	Min.	Тур.	Max.	Units
Weight	Wt	-	80	-	g

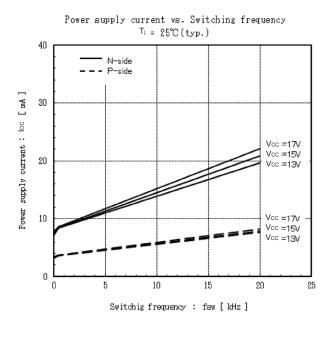
■ Block Diagram

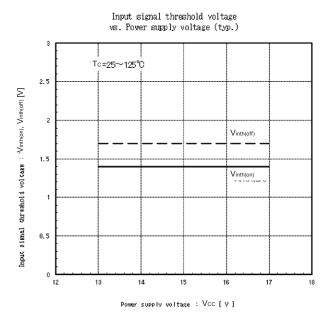


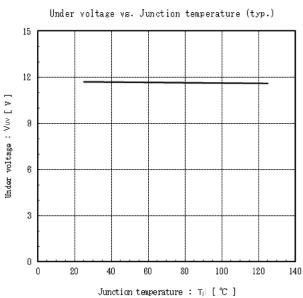
Pre-drivers include following functions

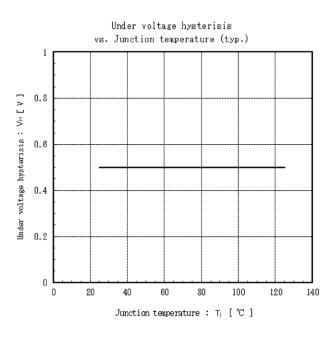
- 1. Amplifier for driver
- 2. Short circuit protection
- 3. Under voltage lockout circuit
- 4. Over current protection
- 5. IGBT chip over heating protection

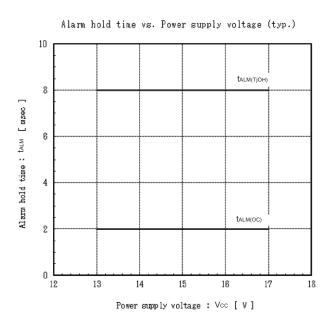
■ Characteristics (Representative)

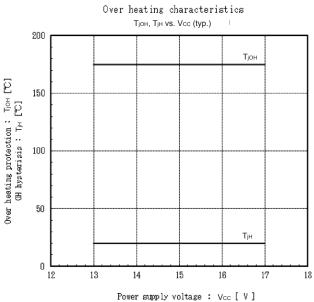




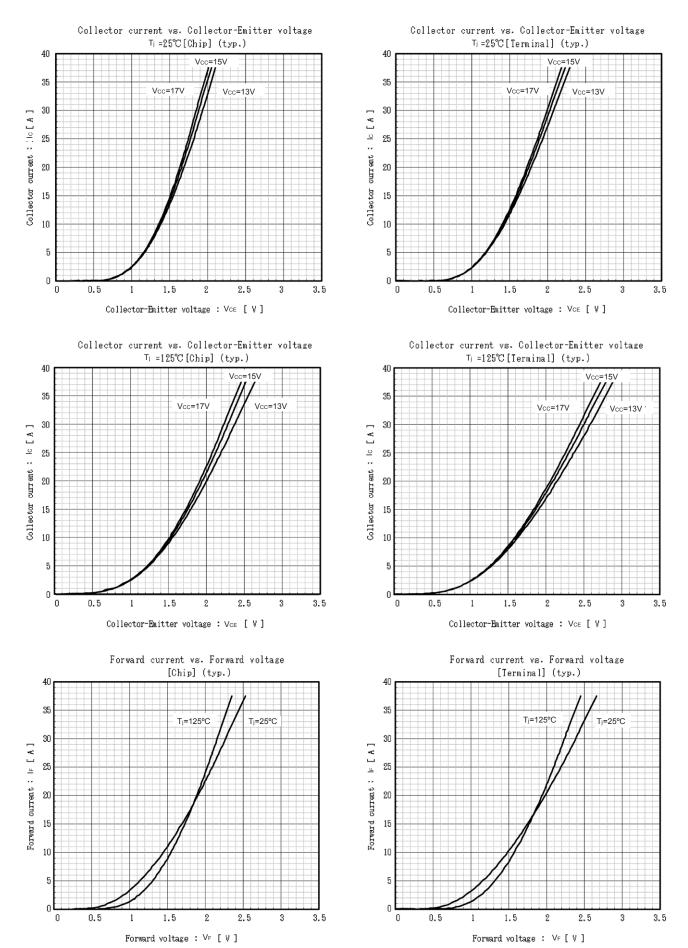


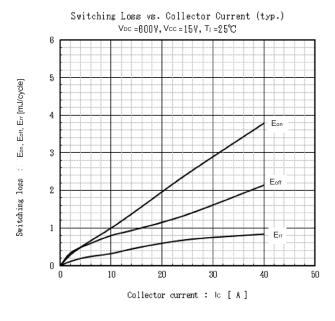


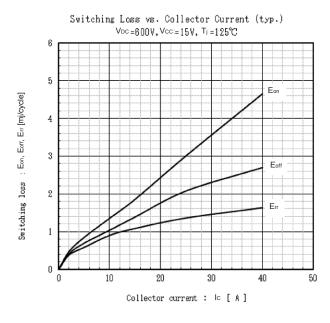


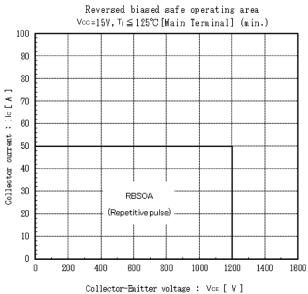


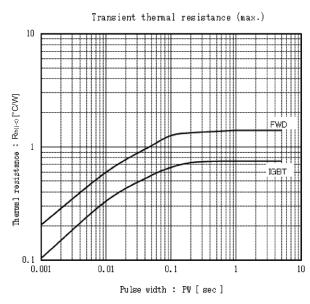
Inverter

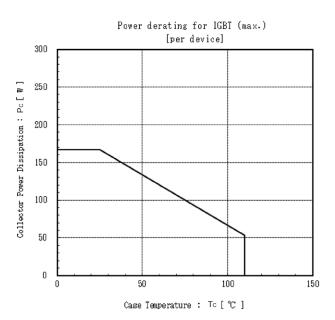


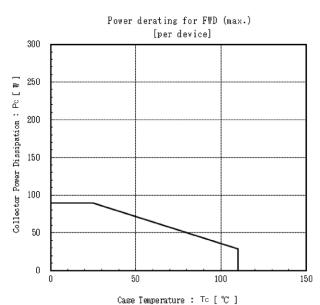


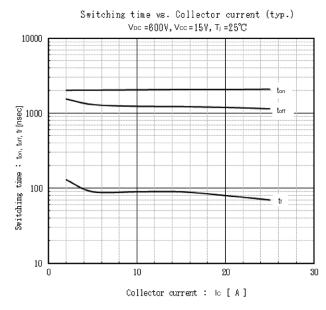


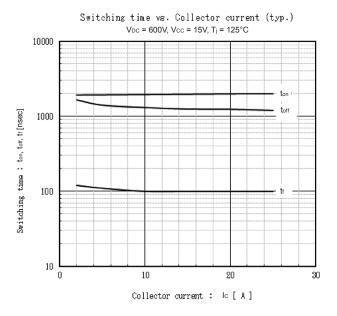


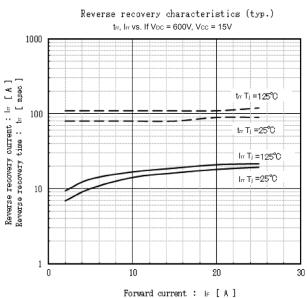


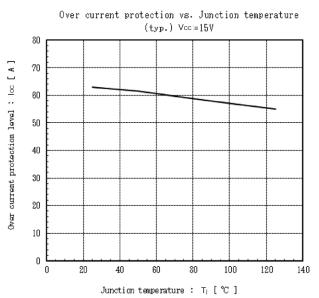




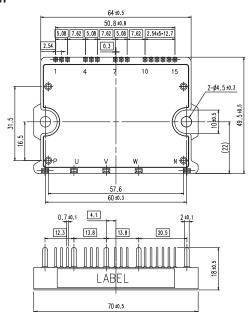


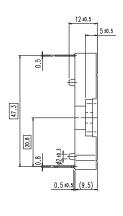






■ Outline Drawings, mm





Weight: 80g(typ.)

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IGBT Modules

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